

8th "Trento" Workshop on Advanced Silicon Radiation Detectors (3D and p-type)

Monday 18 February 2013

Planar Sensors 2 - "Stringa" Conference Hall (16:40 - 18:30)

-Conveners: Gianluigi Casse

| time | [id] title | presenter |
|-------|--|-------------------------|
| 16:40 | [33] Study of Behaviour of n-in-p Silicon Sensor Structures Before and After Irradiation | UNNO, Yoshinobu |
| 17:00 | [13] Fabrication of new p-type pixel detectors with enhanced multiplication effect in the n-type electrodes. | BASELGA BACARDIT, Marta |
| 17:20 | [37] Charge collection studies on special diodes from RD50 multiplication run | KRAMBERGER, Gregor |
| 17:40 | [3] Ultra-Fast Silicon Sensors | SADROZINSKI, Hartmut |
| 18:00 | [44] Discussion | |